

L Number	Hits	Search Text	DB	Time stamp
1	544	345/76.ccls.	USPAT; US-PGPUB	2003/06/24 14:31
2	62	345/76.ccls. and p-channel and n-channel	USPAT; US-PGPUB	2003/06/24 18:10
3	196	345/76.ccls. and transistors	USPAT; US-PGPUB	2003/06/24 14:47
4	151	(345/76.ccls. and transistors) not (345/76.ccls. and p-channel and n-channel)	USPAT; US-PGPUB	2003/06/24 15:03
5	123	tam-s\$.in.	USPAT; US-PGPUB	2003/06/24 15:04
6	9	tam-simon.in.	USPAT; US-PGPUB	2003/06/24 15:24
7	1	6369788.pn.	USPAT; US-PGPUB	2003/06/24 15:35
8	1		USPAT	2003/06/24 15:25
9	1		USPAT	2003/06/24 15:25
10	1		USPAT	2003/06/24 15:25
11	1		USPAT	2003/06/24 15:25
12	1		USPAT	2003/06/24 15:26
13	1		USPAT	2003/06/24 15:26
14	1		USPAT	2003/06/24 15:26
15	1		USPAT	2003/06/24 15:26
16	1		USPAT	2003/06/24 15:26
17	1		USPAT	2003/06/24 15:26
18	1		USPAT	2003/06/24 15:26
19	1		USPAT	2003/06/24 15:27
20	1		USPAT	2003/06/24 15:27
21	1		USPAT	2003/06/24 15:27
22	1		USPAT	2003/06/24 15:27
23	1		USPAT	2003/06/24 15:27
24	1		USPAT	2003/06/24 15:27
25	1		USPAT	2003/06/24 15:27
26	1		USPAT	2003/06/24 15:27
27	431	oled	EPO; JPO; DERWENT	2003/06/24 15:36
28	31	oled and transistors	EPO; JPO; DERWENT	2003/06/24 16:17
29	295	345/44-46.ccls.	USPAT; US-PGPUB	2003/06/24 16:27
30	70	345/44-46.ccls. and transistors	USPAT; US-PGPUB	2003/06/24 16:18
31	891	315/169.1.ccls.	USPAT; US-PGPUB	2003/06/24 16:32
32	44	315/169.1.ccls. and p-channel and n-channel	USPAT; US-PGPUB	2003/06/24 16:32
33	1277	315/169.3.ccls.	USPAT; US-PGPUB	2003/06/24 16:36
34	106	315/169.3.ccls. and p-channel and n-channel	USPAT; US-PGPUB	2003/06/24 16:36
35	763	315/169.4.ccls.	USPAT; US-PGPUB	2003/06/24 16:36
36	25	315/169.4.ccls. and p-channel and n-channel	USPAT; US-PGPUB	2003/06/24 16:36
37	30012	p-channel and n-channel	USPAT; US-PGPUB	2003/06/24 18:10
38	92	(p-channel and n-channel) and polysilicon adj thin adj film adj transistors	USPAT; US-PGPUB	2003/06/24 18:15
39	2	((p-channel and n-channel) and polysilicon adj thin adj film adj transistors) and 345/76.ccls.	USPAT; US-PGPUB	2003/06/24 18:15
40	3	((p-channel and n-channel) and polysilicon adj thin adj film adj transistors) and 315/169.1.ccls.	USPAT; US-PGPUB	2003/06/24 18:21
41	0	((p-channel and n-channel) and polysilicon adj thin adj film adj transistors) and oeld	USPAT; US-PGPUB	2003/06/24 18:16

42	2	((p-channel and n-channel) and polysilicon adj thin adj film adj	USPAT;	2003/06/24 18:16
43	0	transistors) and oel 6011532.pn. and polysilicon	US-PGPUB USPAT; US-PGPUB	2003/06/24 18:20